

## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER OF PATENTS AND TRADEMARKS
Washington, D.C. 20231
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/941,676	08/30/2001	Fumio Odaka	106659.01	9538	
25944 7	590 01/15/2003				
OLIFF & BERRIDGE, PLC			EXAMINER		
P.O. BOX 19928					
ALEXANDRI	A, VA 22320		FIORILLA, CHRISTOPHER A		
			ART UNIT	PAPER NUMBER	
			1731		
			DATE MAILED: 01/15/2003	2	

Please find below and/or attached an Office communication concerning this application or proceeding.

				_ 82
		Application No.	Applicant(s)	
Office Action Summary		09/941,676	ODAKA ET AL.	
		Examiner	Art Unit	
		Christopher A. Fiorilla	1731	
Period fo	• •		·	ess
THE I - Exter after - If the - If NO - Failui - Any r	ORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. Period for reply specified above is less than thirty (30) days, a repleperiod for reply is specified above, the maximum statutory period re to reply within the set or extended period for reply will, by statute eply received by the Office later than three months after the mailing displaying terms adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be till be within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDON.	mely filed  ys will be considered timely.  the mailing date of this com  FD (35 U.S.C. 8.133)	munication.
1)	Responsive to communication(s) filed on			
2a)□		 nis action is non-final.		
3) Dispositi	Since this application is in condition for allows closed in accordance with the practice under on of Claims	ance except for formal matters, p	rosecution as to the 453 O.G. 213.	merits is
4)🖂	Claim(s) 12-19 is/are pending in the application	on.		
4	4a) Of the above claim(s) is/are withdra	wn from consideration.		
	Claim(s) is/are allowed.			
	Claim(s) <u>12-19</u> is/are rejected.			
	Claim(s) is/are objected to.			
	Claim(s) are subject to restriction and/o	or election requirement		
	on Papers			
9)[] 7	he specification is objected to by the Examine	ır.		
10)[] T	he drawing(s) filed on is/are: a)□ acce	pted or b)⊡ objected to by the Exa	miner.	
	Applicant may not request that any objection to the	e drawing(s) be held in abeyance. S	see 37 CFR 1.85(a).	
11)[ T	he proposed drawing correction filed on	_ is: a) ☐ approved b) ☐ disappro	oved by the Examiner.	
	If approved, corrected drawings are required in rep			
12) 🗌 T	he oath or declaration is objected to by the Ex	aminer.		
Priority u	nder 35 U.S.C. §§ 119 and 120			
13) 🗌	Acknowledgment is made of a claim for foreigr	n priority under 35 U.S.C. § 119(a	a)-(d) or (f).	
	All b) Some * c) None of:		, , , , ,	
	1. Certified copies of the priority documents	s have been received.		
:	2. Certified copies of the priority documents		on No.	
	3. Copies of the certified copies of the prior application from the International Bure the attached detailed Office action for a list	rity documents have been receive reau (PCT Rule 17.2(a)).	ed in this National St	age
	cknowledgment is made of a claim for domestic			plication).
a)	☐ The translation of the foreign language pro cknowledgment is made of a claim for domesti	visional application has been rec	eived.	
		<b>,,</b> □		
2) 🔲 Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) ation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal f	r (PTO-413) Paper No(s). Patent Application (PTO-1	 52)
Patent and Trac O-326 (Rev.		tion Summary	Part of Pa	mar No. 7

Application/Control Number: 09/941,676

Art Unit: 1731

1. Claims 12-19 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 12, the phrase "carbon contained in the molded body" has no antecedent basis.

The source of the carbon is unclear.

In claim 14, the last portion of the claim (i.e. "effecting post-treatment...) is written such that the heating schedule is unclear.

Claim 18 is indefinite in that it refers to an organic substance impregnated in the molded body but there is no positive impregnating step recited in the claims.

Claim 18 is indefinite in that the basis of the percentage is undefined (i.e. are the percentages based on weight?).

2. The disclosure is objected to because of the following informalities:

On page 7, line 6, the sentence "A preferable example of solid carbon sources is silicon oxide" appears to be inaccurate. Silicon oxide is not a carbon source.

On page 17, line 3, "molted" should be changed to \*\* molten \*\*.

Appropriate correction is required.

3. Claims 12-19 are rejected under 35 U.S.C. 112, first paragraph, because the specification, while being enabling for a process wherein the molded body is impregnated with an organic substance consisting of at least one kind of carbon source (page 15, lines 7-10), does not reasonably provide enablement for the process as generically claimed. The specification does

Application/Control Number: 09/941,676 Page 3

Art Unit: 1731

not enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to practice the invention commensurate in scope with these claims.

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

5. Claim 12 is rejected under 35 U.S.C. 102(b) as being clearly anticipated by Kojima et al. (5,589,116).

Kojima et al. teaches the claimed process of producing a silicon carbide sintered body.

The process disclosed by Kojima et al. includes the steps of:

preparing a slurry by dispersing silicon carbide powder in a solvent; forming a molded body by pouring the slurry into a mold; effecting calcination of the slurry in a vacuum; and impregnating the pores in the calcined body with molten silicon.

See col. 11, lines 50-67. Kojima et al. also discloses that the SiC powder has an average particle size of 5 μm (col. 11, line 44); calcinations may be carried out at 500-2000°C C (col. 9, line 33); a nitrogen source is added during the slurry formation (ammonium) and the silicon carbide powder impurity amounts (Table 1).

6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are

Application/Control Number: 09/941,676 Page 4

Art Unit: 1731

such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- 7. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 8. Claims 12,13 and 17-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kriegsmann et al. (6,228,283) in view of Ohno et al. (4,284,431).

Kriegsmann et al. teaches the basic claimed process of manufacturing a silicon carbide body. The process disclosed by Kriegsmann et al. includes the steps of:

preparing a slurry by dispersing silicon carbide powder in a solvent; forming a molded body by pouring the slurry into a mold; effecting calcination of the slurry in a vacuum; and impregnating the pores in the calcined body with molten silicon.

See e.g. col. 5. Kriegsmann et al. also discloses that the SiC powder has an average particle size between 0.1 and 10μm (col. 5, line 30); a nitrogen source is added during the slurry formation (ammonium) and calcination (sintering) may be carried out at 1700°C (col. 5, line 39).

Application/Control Number: 09/941,676

Art Unit: 1731

Kriegsmann et al. discloses impregnating the body with phenol resin (col. 5, line 47) but does not disclose that the polymer has a carbon content of 10-30%. Ohno et al. discloses phenol resins with carbon contents within this range. See e.g. Figure 2 and elsewhere. It would have been obvious to one skilled in the art at the time of the invention to use this type of resin in the process of Kriegsmann et al. in view of the generic disclosure therein.

9. Claims 12-17 and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kojima et al. (5,589,116) in view of Takahashi et al. (6,217,969).

Kojima et al. teaches the claimed process of producing a silicon carbide sintered body.

The process disclosed by Kojima et al. includes the steps of:

preparing a slurry by dispersing silicon carbide powder in a solvent; forming a molded body by pouring the slurry into a mold; effecting calcination of the slurry in a vacuum; and impregnating the pores in the calcined body with molten silicon.

See col. 11, lines 50-67. Kojima et al. also discloses that the SiC powder has an average particle size of 5 µm (col. 11, line 44); calcinations may be carried out at 500-2000°C C (col. 9, line 33); a nitrogen source is added during the slurry formation (ammonium) and the silicon carbide powder impurity amounts (Table 1).

Kojima et al. does not disclose the method of forming silicon carbide powder as recited in claims 14 and 15. Takahashi et al. discloses this method of forming silicon carbide powder. See cols. 5-6. It would have been obvious to one having ordinary skill in the art at the time of the invention to use this method to prepare the silicon carbide for use in the process of Kojima et al. in view of the requirement therein that the SiC be of high purity.

Application/Control Number: 09/941,676

Art Unit: 1731

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Christopher A. Fiorilla whose telephone number is 703-308-0674. The examiner can normally be reached on M-F, 6:30am-3:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Steven P. Griffin can be reached on 703-308-1164. The fax phone numbers for the organization where this application or proceeding is assigned are 703-305-7718 for regular communications and 703-305-3599 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0651.

> Christopher A. Fiorilla **Primary Examiner**

Art Unit 1731